
HVC357

Variable Capacitance Diode for VCO

HITACHI

ADE-208-417 (Z)

Rev. 0

Nov. 1995

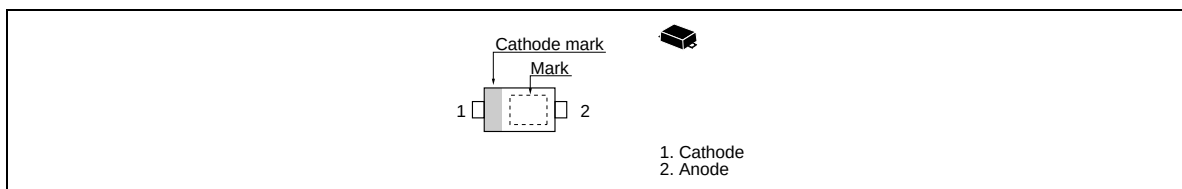
Features

- Low series resistance. ($r_s = 0.35\Omega_{\text{max}}$)
- Ultra small Flat Package (UFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVC357	J	UFP

Outline



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Value	Unit
Reverse voltage	V_R	10	V
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

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Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	I_{R1}	—	—	10	nA	$V_R = 10V$
	I_{R2}	—	—	100		$V_R = 10V, T_a = 60^\circ C$
Capacitance	C_1	19.5	—	23.5	pF	$V_R = 1V, f = 1MHz$
	C_2	14.3	—	17.6		$V_R = 2V, f = 1MHz$
Capacitance ratio	n	1.3	—	—	—	C_1/C_2
Series resistance	r_s	—	—	0.35	Ω	$V_R = 1V, f = 470MHz$

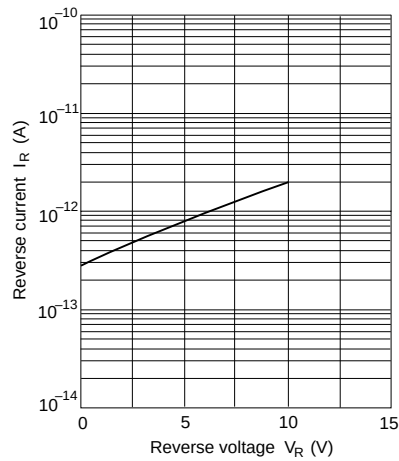
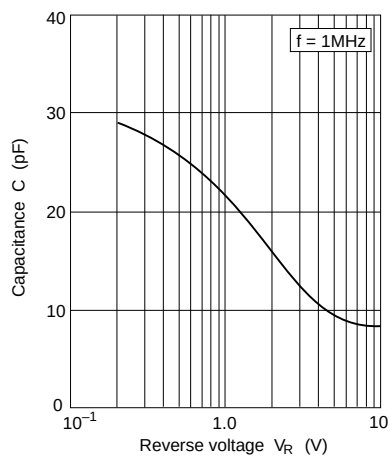
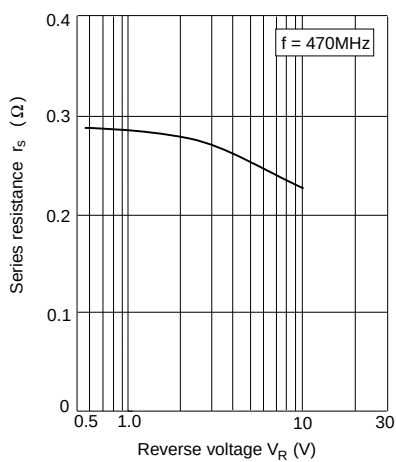


Fig.1 Reverse current Vs. Reverse voltage

**Fig.2 Capacitance Vs. Reverse voltage****Fig.3 Series resistance Vs. Reverse voltage**

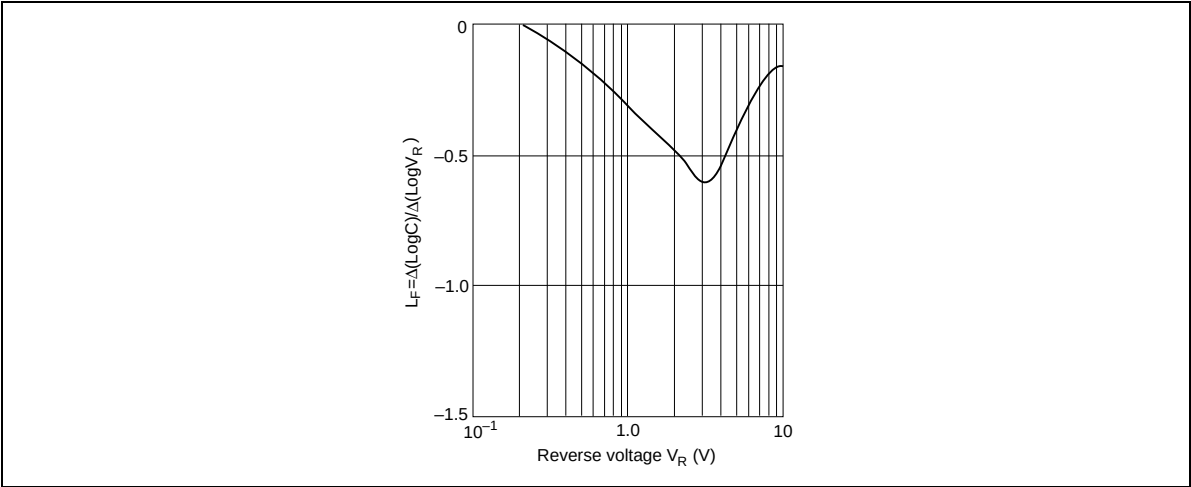


Fig.4 Linearity factor Vs. Reverse voltage

Package Dimensions

